



UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER OF PATENTS AND TRADEMARKS Washington, D.C. 20231 www.uspto.gov

APPLICATION NO. FILING DATE FIRST NAMED INVENTOR ATTORNEY DOCKET NO. CONFIRMATION NO. 09/920,927 08/03/2001 Shinichiroh Ikemasu 970607A 9951 23850 7590 12/28/2001 ARMSTRONG, WESTERMAN, HATTORI, **EXAMINER** MCLELAND & NAUGHTON, LLP 1725 K STREET, NW, SUITE 100 WEISS, HOWARD WASHINGTON, DC 20006 ART UNIT PAPER NUMBER 2814 DATE MAILED: 12/28/2001 Due March 28, 2002 First Action ARMSTRONG, WESTERMAN; HATTORI

Please find below and/or attached an Office communication concerning this application or proceeding.

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FEBIL 2002
TECHNOLOGY CERNER 2800

2-6-02

FEB P2002	Application N .	Applicant(s)
Offic Action Summary	09/920,927	IKEMASU ET AL.
· Oπic Action Summary ?	Examiner	Art Unit
	Howard Weiss	2814
Th MAILING DATE of this communication app Period for Reply	ears on the cover sheet with th	correspondence address
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. If the period for reply specified above is less than thirty (30) days, a reply If NO period for reply is specified above, the maximum statutory period w Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b). Status 1) Responsive to communication(s) filled on 8/3/ 2a) This action is FINAL. 2b) This 3) Since this application is in condition for allowed closed in accordance with the practice under a closed. Claim(s) 1-19 and 62-79 is are pending in the 4a) Of the above claim(s) is/are allowed. Claim(s) 1-19 and 62-79 is are rejected. Claim(s) 1-19 and 62-79 is are rejected. Claim(s) 1-19 and 62-79 is are rejected. Claim(s) are subject to restriction and/or	36(a). In no event, however, may a reply be tin	nely filed
1) Responsive to communication(s) filed on 8/3/	<u>01</u> .	
2a) ☐ This action is FINAL . · 2b) ☑ Thi	is action is non-final.	
3) Since this application is in condition for allowa closed in accordance with the practice under a	nce except for formal matters, p Ex parte Quayle, 1935 C.D. 11, 4	rosecution as to the merits is
Disposition of Claims		有有
4)⊠ Claim(s) 1-19 and 62-79 is/are pending in the	application.	
4a) Of the above claim(s) is/are withdraw	vn from consideration.	PECENED PED 11 2007 PED 11 2007 PED 11 2007
5) Claim(s) is/are allowed.		1922
6)⊠ Claim(s) <u>1-19 and 62-79</u> is (are rejected.		20
7) Claim(s) is/are objected to.		800
8) Claim(s) are subject to restriction and/or	election requirement.	
Application Papers		
9)⊠ The specification is objected to by the Examiner	;	
10)⊠ The drawing(s) filed on 03 August 2001 is/are: a	a)∐ accepted or b)⊠ objected to b	y the Examiner.
Applicant may not request that any objection to the	drawing(s) be held in abeyance. S	ee 37 CFR 1.85(a).
11) The proposed drawing correction filed on	is: a) ☐ approved b) ☐ disappro	oved by the Examiner.
If approved, corrected drawings are required in rep	ly to this Office action.	
12) The oath or declaration is objected to by the Exa	aminer.	
Priority under 35 U.S.C. §§ 119 and 120		
13) Acknowledgment is made of a claim for foreign	priority under 35 U.S.C. § 119(a	n)-(d) or (f).
a)⊠ All b)☐ Some * c)☐ None of:		
 Certified copies of the priority documents 	s have been received.	
2. Certified copies of the priority documents	have been received in Applicati	on No. <u>08/876,908</u> .
3. Copies of the certified copies of the prior application from the International Bur * See the attached detailed Office action for a list of the certified copies of the prior application for a list of the certified copies of the prior application for a list of the certified copies of the prior application for a list of the certified copies of the prior application for a list of the certified copies of the prior application for a list of the prior application for a list of the prior application for a list of the prior application from the list of the	eau (PCT Rule 17.2(a)).	·
14) Acknowledgment is made of a claim for domestic	•	
a) ☐ The translation of the foreign language prov 15)☑ Acknowledgment is made of a claim for domestic	visional application has been rec	eived.
Attachment(s)	- p 4	· · · · · · · · · · · · · · · · · · ·
) Notice of References Cited (PTO-892) P) Notice of Draftsperson's Patent Drawing Review (PTO-948) Notice of Draftsperson's Patent (S) (PTO-1449) Paper No(S) 4.	5) Notice of Informal I	r (PTO-413) Paper No(s) Patent Application (PTO-152)

Art Unit: 2814

Attorney's Docket Number: 970607A

Filing Date: 8/3/01

Continuing Data: Division of 08/876,908 (6/16/97)

Claimed Foreign Priority Date: 7/18/96 (JPX)

Applicant(s): Ikemasu et al. (Okawa)

Examiner: Howard Weiss

Priority

Acknowledgment is made of applicant's claim for foreign priority under 35 U.S.C. 119(a)-(d). The certified copy has been filed in parent Application No. 08/876,908, filed on 6/16/97.

Drawings

 The drawings are objected to as failing to comply with 37 CFR 1.84(p)(5) because they do not include the following reference sign(s) mentioned in the description: Line A-A' as mentioned on Page 20 Lines 1 and 2 of the Specification. Correction is required.

Specification

- 3. The disclosure is objected to because of the following informalities: On Page 20 Line 21, after "1995" insert ---now U.S. Patent No. 5,780,907---. Appropriate correction is required.
- 4. The title of the invention is not descriptive. A new title is required that is clearly indicative of the invention to which the claims are directed.

Claim Objections

5. The claims are objected to because they lack a proper introduction. The present Office practice is to insist that each claim must be the object of a sentence starting with "I (or we) claim", "The invention claimed is" or the equivalent. Please see MPEP § 608.01(m).

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6. In Claims 66 and 67, ---a--- should be inserted between "of" and "dynamic" in Line 2 of each claim.

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Claim Rejections - 35 USC § 112

- 7. The following is a quotation of the second paragraph of 35 U.S.C. 112:
 - The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.
- 8. Claims 1 to 19 and 62 to 79 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.
- 9. Claims 1 and 3 are rejected under 35 U.S.C. 112, second paragraph, as being incomplete for omitting essential elements, such omission amounting to a gap between the elements. See MPEP § 2172.01. The omitted elements are: a second insulating film in Lines 3 and 4 of each claim. There is no antecedent basis for the third insulating film after the first.
- 10. Claims 2, 4, 5, 7, 13, 63, 66, 67 and 73 recite the limitation "said conductive pattern." There is insufficient antecedent basis for this limitation in the claims.
- 11. Claim 8 defines "a third insulting film having etching characteristics different from silicon nitride." However, "a third insulating made of silicon nitride" had been defined in the independent Claim 1 from which Claim 8 depends and, therefore, raises conflicts making the claimed invention unclear.
- 12. Claim 9 recites the limitation "the surface of said third insulating film" in Line 2. It is unclear which "third insulating film" is being referred to in the claim.

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13. Claims 18 and 19 recite the limitation "said storage capacitor." There is insufficient antecedent basis for this limitation in the claims.

- 14. Claim 19 recites the limitation "said silicon nitride layer" without specify which of the silicon nitride layers covering which of wiring patterns is being referred to.
- 15. Claim 70 recites the limitation "the contact area" in Line 2. There is insufficient antecedent basis for this limitation in the claim.

Claim Rejections - 35 USC § 103

- 16. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

17. Claims 1 to 13, 16, 17, 62 to 65 and 68 to 73 are rejected under 35 U.S.C. 103(a) as being unpatentable over Hayashide in view of Meguro et al.

Hayashide shows most aspects of the instant invention (e.g. Figure 1) including:

a semiconductor substrate 1 having an uppermost insulating film 3

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- a lamination of a first conductive film 4 of tungsten silicide, a first insulating film 5,
 a third insulting film 9 of silicon nitride or 8 not of silicon nitride said lamination
 being a gate of a MIS transistor
- second insulating films 7 formed on the sidewalls of the lamination and made of silicon dioxide
- fourth insulating films 10 contiguous with the third insulating film and covering said first film
- an interlevel insulating film 12 with an aperture formed through said interlevel film and filled with a second conductive film 14 and being parallel to said substrate surface
- a fifth insulating film 18, an upper conductive pattern 25 and a sixth insulating film
 28 covering the sidewalls of said upper conductive pattern and a seventh insulating film (thin layer above 28) made of silicon nitride
- a field insulating film 2 with a wiring pattern 4 formed on the field insulating film and covered by a film of silicon nitride 9

Hayashide does not show the second insulating film having a thickness smaller the first, the first insulating film cover in the sidewalls and top of the first conductive film extending under the bottom of said second insulating film and the second insulating film define said aperture. Meguro et al. teaches (e.g. Figure 1(B)) to form a first insulating film 6 under the bottom of a second or fourth insulating films 8A,B and defining an aperture 9 to improve the strength of the electrodes with respect to external forces (Column 2 Lines 53 to 57). It would have been obvious to a person of ordinary skill in the art at the time of invention to form a first insulating film under the bottom of a second or fourth insulating films and defining an aperture as taught by Meguro et al. in the device of Hayashide to improve the strength of the electrodes with respect to external forces.

18. Claims 14, 15, 18, 19, 66, 67 and 74 o 79 are rejected under 35 U.S.C. 103(a) as being unpatentable over Hayashide in view of Meguro et al., as applied to Claims 1 and 3 above, and further in view of Lee et al.

Hayashide in view of Meguro et al. show most aspects of the instant invention (Paragraph 17) except for the configuration being part of a Dram with a capacitor as claimed. Lee et al. teach (e.g. Figure 1) that is common, and therefore obvious, to have a DRAM with a capacitor as claimed in a mutli-layered circuit as taught by Hayashide in view of Meguro et al. (see Abstract).

Conclusion

- 19. Papers related to this application may be submitted directly to Art Unit 2814 by facsimile transmission. Papers should be faxed to Art Unit 2814 via the Art Unit 2814 Fax Center located in Crystal Plaza 4, room 3C23. The faxing of such papers must conform with the notice published in the Official Gazette, 1096 OG 30 (15 November 1989). The Art Unit 2814 Fax Center number is (703) 308-7722 or -7724. The Art Unit 2814 Fax Center is to be used only for papers related to Art Unit 2814 applications.
- 20. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Howard Weiss at (703) 308-4840 and between the hours of 8:00 AM to 4:00 PM (Eastern Standard Time) Monday through Friday or by e-mail via Howard.Weiss@uspto.gov.

Any inquiry of a general nature or relating to the status of this application should be directed to the Group 2800 Receptionist at (703) 308-0956.

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21. The following list is the Examiner's field of search for the present Office Action:

Field of Search	- Date -
U.S. Class / Subclass(es): 257/306, 758	12/19/01
Other Documentation: PLUS Analysis Report	12/10/01
Electronic Database(s): EAST, IEL	12/19/01

Howard Weiss
Patent Examiner
Art Unit 2814

HW/hw 21 December 2001 INFORMATION DISCLOSURE CITATION

PTO-1449

Atty. Docket No. 970607A

Divisional of S.N. 08/876,908

Applicant(s): IKEMASU et al.

FEB 0 8 2002

Filing Date: Herewith

Group Art Unit: To Be Assigned

U.S. PATENT DOCUMENTS

Examiner Initial		Document No.	Name	Date	Class	Subclass	Filing Date
CAN MARKAGO	AA AB AC AD AE AF AG	5,732,009 5,612,254 5,573,965 5,661,344 5,302,551 5,061,985 5,036,370	Tadaki et al. Mu et al. Chen et al. Havemann et al. Iranmanesh et al. Meguro et al. Miyago et al.	3/24/98 3/18/97 11/12/96 8/26/97 4/12/94 10/29/91 7/30/91			RECEIVED FEB 11 2032 FEB 11 2032

FOREIGN PATENT DOCUMENTS

- Charles	Document No.	Date	Country	Translation (Yes or No)
AH J	TP 6-97190	4/8/94	Japan	(======================================
AI J	P 9-36325	2/7/97	Japan	
AJ 5	8-115859	7/9/83	Japan	
AK 3	-155663	7/3/91	Japan	

INFORMATION DISCLOSURE CITATION PTO-1449

Atty. Docket No. 970607A

Divisional of S.N. 08/876,908

Applicant(s): IKEMASU et al.

Filing Date: Herewith

Group Art Unit: To Be Assigned

OTHER DOCUMENTS

A.	0	Tomihisa MIZUNO et al.; IEEE Transactions on Electron Devices, Vol. 38, No. 3 pp.584-591; March 1991.
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Examiner	22	Date Considered 12/21/01

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Application/Control No. Applicant(s)/Patent Under Reexamination IKEMASU ET AL. Examiner Howard W iss Applicant(s)/Patent Under Reexamination IKEMASU ET AL. Page 1 of 1

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	А	US-5,500,558	03-1996	Hayashide	257/758
	В	US-			
	С	US-			1
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FOREIGN PATENT DOCUMENTS

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NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Lee, K.P., et al., "A Process Technology for 1 Giga-Bit DRAM", 10-13 Dec. 1995, IEDM 95, pp.907-910
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).) Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.